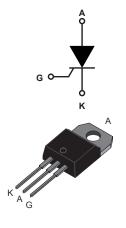


## High temperature 16 A 600 V TO220 thyristor SCRs



TO-220AB

#### **Features**

- High junction temperature: T<sub>j</sub> = 150 °C
- High noise immunity dV/dt = 1000V/µs up to 150 °C
- Gate triggering current I<sub>GT</sub> = 10 mA
- Peak off-state voltage V<sub>DRM</sub>/V<sub>RRM</sub> = 600 V
- High turn-on current rise dI/dt = 100 A/µs
- ECOPACK<sup>®</sup>2 compliant

## **Applications**

- · Motorbike voltage regulator circuits
- · Inrush current limiting circuits
- · Motor control circuits and starters
- · Solid state relays

## **Description**

Thanks to a junction temperature  $T_j$  up to 150 °C and a non-isolated TO-220 package, the TN1610H-6T offers high thermal performance operation up to 16 A rms.

The trade-off between the device's noise immunity (dV/dt = 1 kV/ $\mu$ s), its gate triggering current (I<sub>GT</sub> = 10 mA) and its turn-on current rise (dI/dt = 100 A/ $\mu$ s) allows the design of robust and compact control circuits for voltage regulators in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances and inrush current limiting circuits.

Product status	
TN1610H-6T	

Product summary		
Order code	TN1610H-6T	
Package	TO-220AB	
$V_{DRM}/V_{RRM}$	600 V	
I <sub>GT</sub>	10 mA	



# 1 Characteristics

Table 1. Absolute maximum ratings (limiting values),  $T_j = 25$  °C unless otherwise specified

Symbol	Р	Value	Unit				
I <sub>T(RMS)</sub>	RMS on-state current (180 ° conduction angle)				А		
	I <sub>T(AV)</sub> Average on-state current (180 ° conduction angle)			T <sub>c</sub> = 133 °C	T <sub>c</sub> = 133 °C	10	
$I_{T(AV)}$			T <sub>c</sub> = 138 °C	8	Α		
			T <sub>c</sub> = 142 °C	6			
<b>I</b>	Non repetitive surge peak on state curre	ont (T. initial = 25 °C)	$t_p = 8.3 \text{ ms}$	153	_		
ITSM	Non repetitive surge peak on-state curre	on-state current (T <sub>j</sub> initial = 25 °C)		140	Α		
l <sup>2</sup> t	$I^2$ t value for fusing, ( $T_j$ initial = 25 °C) $t_p$ = 10 ms				A <sup>2</sup> s		
dl/dt	I <sub>G</sub> = 2 x I <sub>GT</sub> , tr ≤ 100 ns				Λ/μο		
ui/ut	Critical rate of rise of on-state current			100	A/µs		
$V_{DRM}/V_{RRM}$	Repetitive peak off-state voltage			600	V		
$I_{GM}$	Peak gate current	t <sub>p</sub> = 20 μs	T <sub>j</sub> = 150 °C	4	Α		
$P_{G(AV)}$	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$				W		
T <sub>stg</sub>	Storage junction temperature range				°C		
Tj	Maximum operating junction temperature				°C		
T <sub>I</sub>	Maximum lead temperature soldering du	260	°C				

Table 2. Electrical characteristics ( $T_j$  = 25 °C unless otherwise specified)

Symbol	Test conditions					
la-			Тур.	4.5	mA	
I <sub>GT</sub>	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Max.	10	IIIA	
V <sub>GT</sub>			Max.	1.3	V	
V <sub>GD</sub>	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150 ^{\circ}\text{C}$				V	
I <sub>H</sub>	I <sub>T</sub> = 500 mA, gate open Max.				mA	
IL	$I_G = 1.2 \times I_{GT}$ Max.				mA	
dV/dt	$V_D$ = 402 V, gate open $T_j$ = 150 °C Min				V/µs	
t <sub>gt</sub>	$I_T = 32 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA}, (dI_G/dt) \text{ max} = 0.2 \text{ A/µs}$ Typ.				μs	
tq	$I_T$ = 32 A, $V_D$ = 402 V, $(dI_T/dt)$ OFF = 30 A/ $\mu$ s, $V_R$ = 25 V, $dV_D/dt$ = 40 V/ $\mu$ s $T_j$ = 150 °C Typ.				μs	

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#### **Table 3. Static characteristics**

Symbol	Test conditions			Value	Unit
V <sub>TM</sub>	I <sub>T</sub> = 32 A, t <sub>p</sub> = 380 μs	T <sub>j</sub> = 25 °C	Max.	1.60	V
V <sub>TO</sub>	Threshold voltage	T <sub>j</sub> = 150 °C	Max.	0.82	V
R <sub>D</sub>	Dynamic resistance	T <sub>j</sub> = 150 °C	Max.	25	mΩ
I <sub>DRM</sub> , I <sub>RRM</sub>	$V_D = V_{DRM}$ ; $V_R = V_{RRM}$	T <sub>j</sub> = 25 °C	Max.	5	μA
	VD - VDRM, VR - VRRM	T <sub>j</sub> = 150 °C	ividX.	1.5	mA

## **Table 4. Thermal parameters**

Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub>	Junction to case (DC)	Max.	1.1	°C/W
R <sub>th(j-a)</sub>	Junction to ambient (DC)	Тур.	60	C/VV

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#### 1.1 Characteristics curves

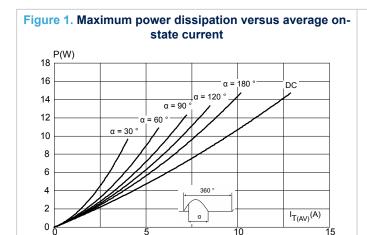


Figure 2. Average and DC on-state current versus case temperature  $I_{T(\underline{A}V)}(A)$ 20 DC 18 16 14 12 α = 180 ° 10 α = 120 8 α = 60 6 α = 30 ° 4 2 T<sub>C</sub>(°C) 0 25 0 50 75 100 125 150

Figure 3. Average and D.C. on state current versus ambient temperature

3.0

1<sub>T(AV)</sub>(A)

2.5

2.0

1.5

1.0

0.5

0.0

2.5

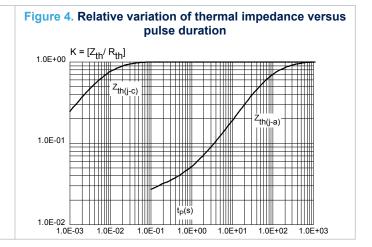
50

75

100

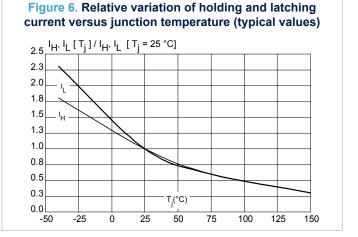
125

150



gate voltage versus junction temperature (typical values)  $I_{GT}$ ,  $V_{GT}$  [  $T_i$  ] /  $I_{GT}$ ,  $V_{GT}$  [  $T_i$  = 25 °C] 2.5 2.0 1.5 1.0 0.5 T<sub>i</sub>(°C) 0.0 -50 -25 0 25 50 75 100 125 150

Figure 5. Relative variation of gate triggering current and



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Figure 7. Relative variation of static dV/dt immunity versus junction temperature (typical values)

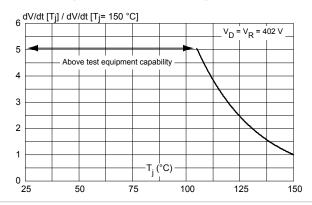


Figure 8. Surge peak on-state current versus number of cycles

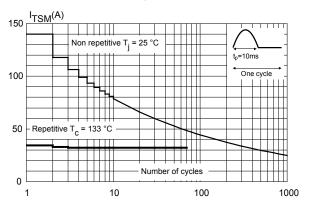


Figure 9. Non repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10 \text{ ms}$ 

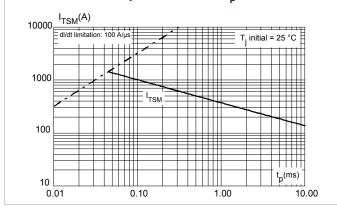


Figure 10. On-state characteristics (maximum values)

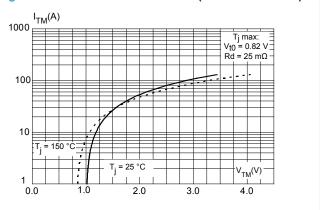
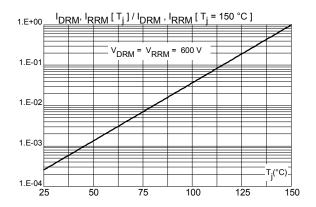


Figure 11. Relative variation of leakage current versus junction temperature ( $t_p < 10 \text{ ms}$ )



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# 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

## 2.1 TO-220AB package information

- Molding compound resin is halogen-free and meets UL standard level V0
- Lead-free package leads finishing
- ECOPACK®2 compliant
- Recommended torque: 0.4 to 0.6 N.m

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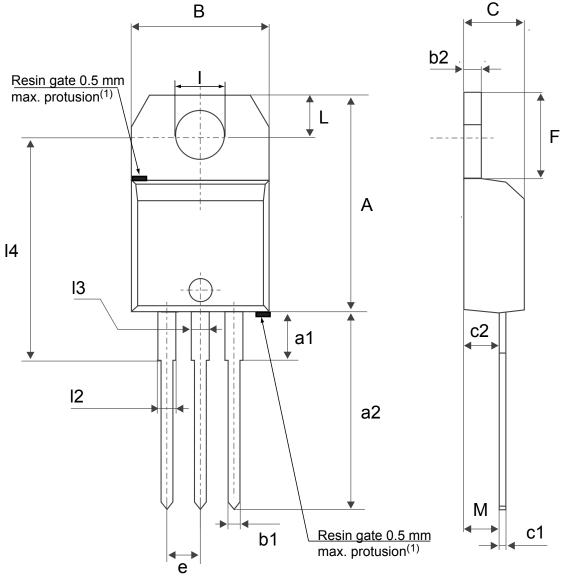


Figure 12. TO-220AB insulated package outline

(1)Resin gate position accepted in one of the two positions or in the symmetrical opposites.

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Table 5. TO-220AB insulated package mechanical data

			D	imensions		
Ref.		Millimeters			Inches <sup>(1)</sup>	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
В	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
С	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
е	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
ı	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
12	1.14		1.70	0.0449		0.0669
13	1.14		1.70	0.0449		0.0669
14	15.80	16.40	16.80	0.6220	0.6457	0.6614
М		2.6			0.1024	

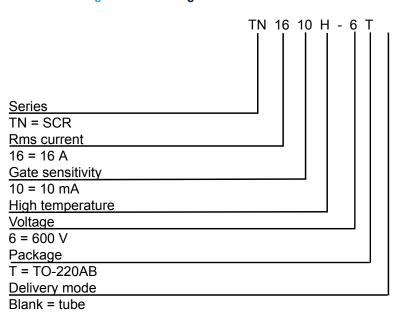
<sup>1.</sup> Inch dimensions are for reference only.

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# 3 Ordering information

Figure 13. Ordering information scheme



**Table 6. Ordering information** 

Or	rder code	Marking	Package	Weight	Base qty.	Delivery mode
TN	I1610H-6T	TN1610H6	TO-220AB	2.3 g	50	Tube

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# **Revision history**

**Table 7. Document revision history** 

Date	Revision	Changes
24-Feb-2015	1	Initial release.
22-Feb-2019	2 Updated Table 4. Thermal parameters.	



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